

# Dropper Type Dual Output Regulator SI-3101S

## Features

- Single input dual output <sub output (5V/0.07A), main output (5V/0.4A)>
- Main output can be externally turned ON/OFF (with ignition switch, etc.)  
<most suitable as memory backup power supply>
- Low standby current ( $\leq 0.8\text{mA}$ )
- Low dropout voltage  $\leq 1\text{V}$
- Built-in constant current type overcurrent, overvoltage and thermal protection circuits
- TO-220 equivalent 5-terminal full-mold package

## Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Conditions
DC input voltage	$V_{IN}$	40	V	
Battery reverse connection	$V_{INB}$	-13 * <sup>6</sup>	V	One minute
Output control terminal voltage	$V_C$	$V_{IN}$	V	
Output current	CH1	$I_{O1}$	0.07 * <sup>1</sup>	A
	CH2	$I_{O2}$	0.4 * <sup>1</sup>	A
Power Dissipation	P <sub>D1</sub>	18	W	With infinite heatsink
	P <sub>D2</sub>	1.5	W	Stand-alone without heatsink
Junction Temperature	$T_J$	-40 to +125	°C	
Operating temperature	$T_{OP}$	-40 to +115	°C	
Storage temperature	$T_{STG}$	-40 to +125	°C	
Junction to case thermal resistance	$\theta_{J-C}$	5.5	°C/W	
Junction to ambient-air thermal resistance	$\theta_{J-A}$	66.7	°C/W	Stand-alone without heatsink

## Electrical Characteristics

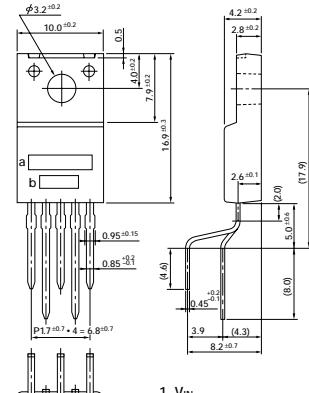
( $T_J=25^\circ\text{C}$ ,  $V_{IN}=14\text{V}$  unless otherwise specified)

Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Input voltage	$V_{IN}$	6 * <sup>2</sup>		35 * <sup>1</sup>	V	
Output voltage	CH1	$V_{O1}$	4.80	5.00	5.20	V $I_{O1}=0.05\text{A}$
	CH2	$V_{O2}$	4.80	5.00	5.20	V $I_{O2}=0.3\text{A}$
Channel-channel voltage difference ( $V_{O1}-V_{O2}$ )	$\Delta V_O$	-0.3		5.30	V	$V_{IN}=0$ to 40V, $I_{O1}$ and $I_{O2}=0\text{A}$ up to load short-circuiting
Dropout voltage	CH1	$V_{DIF1}$		1.0	V	$I_{O1}\leq 0.05\text{A}$
	CH2	$V_{DIF2}$		1.0	V	$I_{O2}\leq 0.4\text{A}$
Line regulation	CH1	$\Delta V_O \text{ LINE1}$	10	30	mV	$V_{IN}=6$ to 18V, $I_{O1}=0.05\text{A}$
	CH2	$\Delta V_O \text{ LINE2}$	10	30	mV	$V_{IN}=6$ to 18V, $I_{O2}=0.3\text{A}$
Load regulation	CH1	$\Delta V_O \text{ LOAD1}$	30	70	mV	$I_{O1}=0$ to 0.05A
	CH2	$\Delta V_O \text{ LOAD2}$	40	70	mV	$I_{O2}=0$ to 0.3A
Ripple rejection	CH1	$R_{REJ1}$	54		dB	$f=100$ to 120Hz
	CH2	$R_{REJ2}$	54		dB	$f=100$ to 120Hz
Quiescent circuit current	$I_Q$			0.8	mA	$I_{O1}=0\text{A}$ , $V_C=0\text{V}$
Overcurrent protection starting current	CH1	$I_{(SI)1}$	0.1 * <sup>3</sup>		A	
	CH2	$I_{(SI)2}$	0.5 * <sup>3</sup>		A	
Output control voltage	Output ON	$V_{CH}$	4.2	4.5	4.8	V
	Output OFF	$V_{CL}$	3.2	3.5	3.8	V
Output control current	Output ON	$I_{CH}$		100	$\mu\text{A}$	$V_C=4.8\text{V}$
	Output OFF	$I_{CL}$	-100		$\mu\text{A}$	$V_C=3.2\text{V}$
Overvoltage protection starting voltage	$V_{OVP}$	35 * <sup>4</sup>			V	
Thermal protection starting temperature	$T_{TSD}$	130 * <sup>5</sup>			°C	

### Notes:

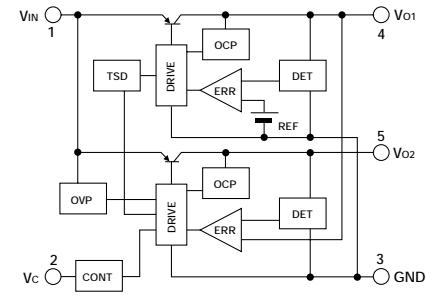
- Since  $P_D(\text{max}) = (V_{IN}-V_O) \cdot I_{O1} + (V_{IN}-V_{O2}) \cdot I_{O2} = 18 \text{ (W)}$ ,  $V_{IN}$  (max),  $I_{O1}$ (max) and  $I_{O2}$ (max) may be limited depending on operating conditions. Refer to the  $T_a$ — $P_D$  curve to compute the corresponding values.
- Refer to the dropout voltage.
- $I_{SI}$  rating shall be the point at which the output voltage  $V_{O1}$  or  $V_{O2}$  ( $V_{IN}=14\text{V}$ ,  $I_{O1}=0.05\text{A}$  or  $I_{O2}=0.3\text{A}$ ) drops to -5%.
- Overvoltage protection circuit is built only in CH2 ( $V_{O2}$  side).
- The indicated temperatures are junction temperatures.
- All terminals, except  $V_{IN}$  and GND, are open.

## External Dimensions (unit: mm)

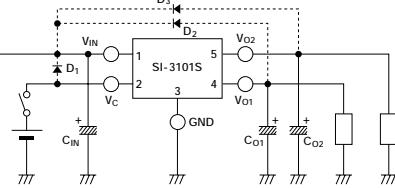


1.  $V_{IN}$   
2.  $V_C$  (on/off)  
3. GND  
4.  $V_{O1}$   
5.  $V_{O2}$   
(Forming No. 1101)

## Equivalent Circuit Diagram



## Standard Circuit Diagram



$C_{O1}$ : Output capacitor (47 to 100 $\mu\text{F}$ , 50V)

$C_{O2}$ : Output capacitor (47 to 100 $\mu\text{F}$ , 50V)

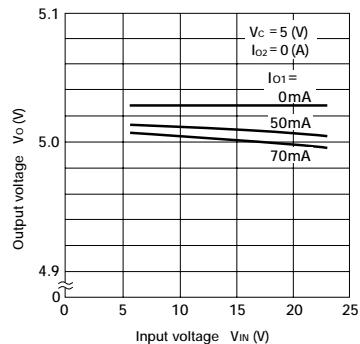
\* $1 C_{IN}$ : Anti-oscillation capacitors (approx. 47 $\mu\text{F}$ ). Tantalum capacitors are recommended, especially at low temperatures.

\* $2 D_1$ ,  $D_2$ ,  $D_3$ : Protection diode.

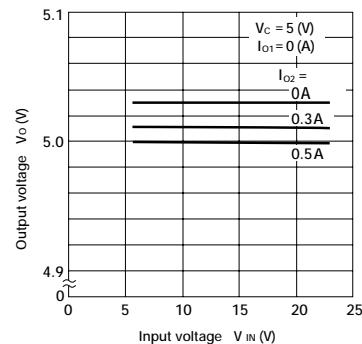
Required as protection against reverse biasing between input and output.

(Recommended diode: Sanken EUZ2.)

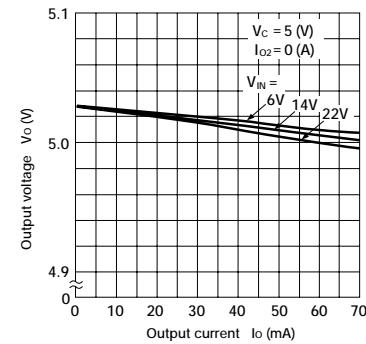
### ■ Line Regulation (1)



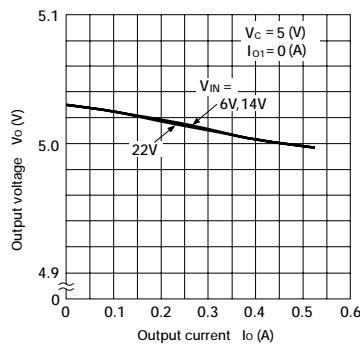
### ■ Line Regulation (2)



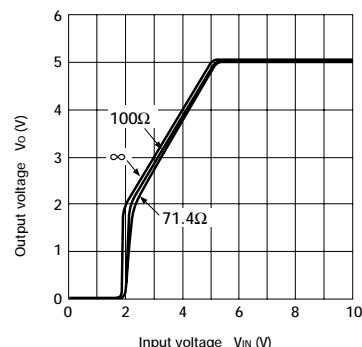
### ■ Load Regulation (1)



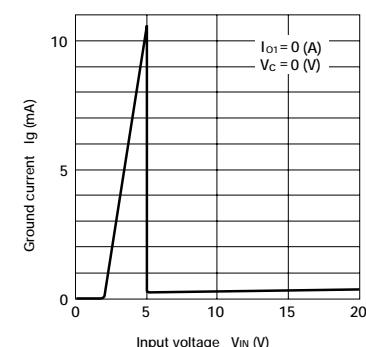
### ■ Load Regulation (2)



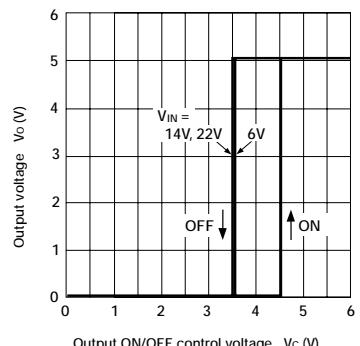
### ■ Rise Characteristics



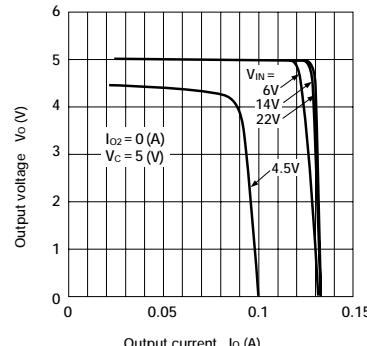
### ■ Circuit Current



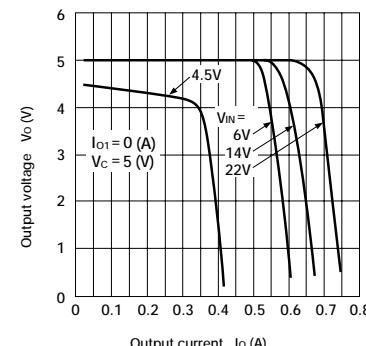
### ■ ON/OFF Control Characteristics



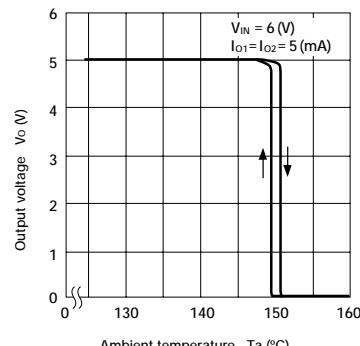
### ■ Overcurrent Protection Characteristics (1)



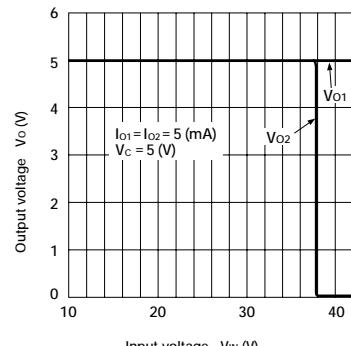
### ■ Overcurrent Protection Characteristics (2)



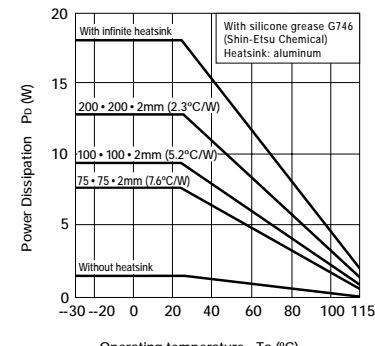
### ■ Thermal Protection Characteristics



### ■ Overvoltage Protection Characteristics



### ■ Ta—P<sub>D</sub> Characteristics



**Note on Thermal Protection Characteristics:**  
The thermal protection circuit is intended for protection against heat during instantaneous short-circuiting. Its operation, including reliability, is not guaranteed for short-circuiting over an extended period of time.